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CHAPTER 1

INTRODUCTION

Energy demand in modern civilization of 20th and 21st century has been abruptly increasing with the population growth and attitude of human beings toward consumption. While avalanche of researches have been conducted to find feasible new energy sources, the efficient use of existing ones gains importance. One of the most outstanding solution is employment of superconducting power cables which transport electrical current without any losses. In future, the superconductors will replace most of the power transmission lines. Energy storage and electronics are two other application fields. The wide spread commercial use of present superconducting materials are limited because of their high cost and technical problems. In attempts to obtain superconductors operating at room temperature and qualified for technological applications, new improvements have repercussion in physics as in the case of MgB₂.

1.1 Historical Introduction

The first observation of superconductivity (Onnes, 1911) phenomenon by Kamerling Onnes in 1911 evoked new enthusiasm in physics. This progress was a product of cumbersome efforts due to very low transition temperature of the first superconducting material, mercury. The transition of mercury from normal state to superconducting state was obtained at 4.2 K. At the beginning of 20th century, even it was a separate research field to attain such a low temperature around 4 K and become possible only after the liquefaction of He by Kamerling Onnes with his coworkers. The first superconductors were elements with extremely low transition temperature, T_c. Nowadays as a result of conducted research, it has been shown that several more compounds behave as superconductivity though practice by design of very powerful magnets. In an attempt to achieve that purpose, he used a Ni alloy coated with Pb-rich superconductor solder. The contrary to his expectation, he was only able to achieve superconductivity up to 500 mT and explained his failure with defects in the wire (Kunzler et al., 1961). Unfortunately

due to the magnetic behavior of the superconductors was seriously miscomprehended, the superconductivity research was not progressive enough to trigger a flurry of application for the following 50 years. (Labalester et al., 2001a)

Even though the interest in superconductors degreased significantly in the beginning of the second half of the 20th century, in 1961 achievement of high critical current densities under a magnetic field of 8.8 T for Nb₃Sn at 4.2 K (Kunzler et al., 1961) was an important step. Since liquid nitrogen is almost ten times cost efficient than liquid He, in 1987, the discovery of high temperature superconductors (HTSCs) (Wu et al., 1987) by a transition temperature above liquefaction of nitrogen at 77 K enhanced curiosity in that field. When ease of reach to 12 K by use of compressors without cryogenics is concerned, that was an important achievement.

Recent observation of superconductivity around 39 K in a simple intermetallic compounds MgB₂ by Akimitsu and his colleagues (Namatsu et al., 2001) resuscitates studies again. This discovery was announced by Akimitsu at a conference in Sendai, Japan in early January 2001. MgB₂ is a known material since early 1950's but only at 2001 it is revealed that MgB₂ is a superconducting material. In two years, a lot of experimental and theoretical studies have been performed to understand the nature of superconductivity in this material.

1.2 Fundamentals of Superconductivity

When the temperature is lowered, the resistivity of metals gets smaller and smaller and eventually reaches a constant value. In some metals, the resistance does not vanish as the temperature approaches 0 K. This is due to scattering of electrons by imperfections and impurities found in the lattice. However, this is not the case for all kind of materials. Materials through which resistance to electric current disappear under a certain critical temperature (T_c) are called as superconductors. Here the critical temperature is defined as the temperature below which a superconductor exhibits superconductivity at zero magnetic field strength and without transporting any current. These materials are in normal state above the critical temperature and in the normal state, they generally have rather poor conductivity. Gold, silver and copper do not superconduct. Ideally, when a supercurrent circulates on a closed loop of a superconductor, the electrons are never dumped. In spite of impurities and imperfections, the current in the loops lasts for a long course of time. An experiment performed by Collins in 1959 exhibited that no observable decrease occurred two and half year after the induction of current around such a superconducting ring (Tinkham, 1975). In addition, File and Mills performed an experiment by use of precision nuclear magnetic resonance method and as a result of experiments they claim that supercurrents in a solenoid last more than 100,000 years (File et al., 1963).

Superconductors are in demand for technological applications on account of not only almost vanishing resistance of them but also magnetic properties as mentioned above. Until some characteristic magnetic field (H_c) superconductors excludes magnetic field lines. If a magnet is placed above a superconductor and cooled below its transition temperature, the magnet levitates. This effect of superconductors was first observed by Meissner and Ochensenfeld and is called as Meissner effect. Magnetic levitation trains (MAGLEVS) are an application of this effect.

Superconductors classified in to two groups as type I and type II with respect to their magnetic behavior. If the whole material completely transforms from normal state to superconducting state under critical temperature and field, it is called as type I. On the other hand, if this transition occurs partially between upper and lower critical field with formation of mixed state, this kind of material is included in the type II class. The mixed state is formed by the existence of both superconducting and normal states together in the same material. These cases in the material occur via formation of vortices, swirling tubes of electrical current induced by an external magnetic field into the surface of a superconducting material. Superconductivity is completely suppressed within these regions. When a current passed through a superconductor in mixed state because of Lorentz Forces and resulting dissipation of energy the vortices are exposed a resistance at right angles to the current flow. (Bishop et al., 1993). The pseudo-resistance resulted from the motion of this volcano shaped structures are undesirable and can be overwhelmed by introducing pinning centers about which more mentioned later.

While type I superconductors are elements and not appropriate for technological applications resulting from their low H_c values, type II superconductors (Feng et al., 2002) are compounds and complex materials with wide area of applications. The upper critical field of type II is much larger than that of type I superconductors. This property is sufficient to extinguish these two classes from each other. Type II superconductors are good candidate materials for magnet applications because of their large upper-critical fields. MgB₂ takes part in type II superconductors and as mentioned above

pining center play an important role in the electrical conduction properties of the material.

1.3 Advantages of MgB₂

The highest transition temperature for conventional alloys and metals was 23 K before the discovery of MgB₂. This value was first attained by Nb₃Ge in 1973 and then one year after by a Y-Pd-B-C compound. According to the present indications MgB₂ promises higher device speeds and higher operating temperature than the already existing electronics based on Nb (Buzea et al., 2001). The MgB₂ bulk material presents several major advantages both with respect to the low temperature superconductors and with respect to the higher temperature superconductors based on cuprates. The major advantage of MgB₂ relative to NbTi and Nb₃Sn is the use of a refrigeration system without cryogenic liquid He (Giunchi et al., 2002). In addition, as reported by Larbalestier et al. in 2001b, the grain connectivity, which means having a link or small distance between grains, associated with MgB₂ is as good as in Nb₃Sn.

Although MgB₂ has relatively low T_c with respect to HTSCs, it has drawn remarkable attention. The reason of this aroused interest can be interpreted as follows: HTSCs are anisotropic in structure and have low critical current densities in long range because of problem in grain connectivity. Furthermore they are very brittle in structure and sensitive to elemental substitutions. By using Ag as cladding materials, they gain ductility. However, this increases cost in applications like tapes and cables. As a result of good grain connectivity in MgB₂ (Larbalestier et al, 2001b) and large coherence lengths relative to HTSCs, the weak links do not form a major concern in the superconductive properties of MgB₂. The coherence length in it is shown to be longer than that in the HTSC cuprates (Finmore et al., 2001). It is about 5.2 nm (Finmore et al., 2001). The supercurrents in MgB_2 show stability with time (Thompson et al., 2001). MgB₂ can be obtained either by reliable rapid synthesis or as commercially available powders. These advantages made this material suitable for commercial applications. Although MgB₂ is also brittle material, it is possible to increase the ductility and malleability of MgB₂ by using cladding materials or fabricating composites. In the selection of materials the effect of elemental substitutions on the superconducting properties of MgB₂ and relatively low decomposition and melting temperature should

be concerned. The substitutions may increase or decrease superconducting properties of MgB₂. They may play role as pinning center and concomitantly increase the J_c.

1.4 The Mechanism of Superconductivity in MgB₂

From some aspects (Choi et al., 2002), MgB₂ is different than ordinary metallic superconductors. The conventional models (Eliashberg, 1960) cannot predict very high transition temperatures such as 40 K. On the other hand, as a result of band structure studies, observation of isotope effect and some related works, it is generally classified as a conventional BCS type superconductor (Choi et al., 2002). BCS type superconductors are materials of which microscopic theory was founded in 1957-1958 by J. Bardeen, L. Cooper, J. Schrieffer. Now this theory is referred as BCS theory. According to the BCS theory, the superconductivity occurs via pairing of electrons as a result of attractive interaction between electrons, mediated by lattice vibrations, phonons. BCS theory is appropriate for the weak-coupling (the strength of coupling with phonon vibrations and electrons) limit and in the strong coupling limit a more general form of it found by Eliashberg is valid (Eliashberg, 1960).

 MgB_2 shows superconductivity at a temperature ~33% higher than the theory seemed to allow (Brumfiel, 2001). To explain such a high transition temperature, several attempts and suggestions were made. MgB_2 might have come from a new class of superconductors or since MgB_2 has a structure with alternating layer of Mg atoms and honeycomb boron layers, as anticipated by BCS theory the light boron atoms might have been a reason for high T_c in MgB_2 (Kortus et al., 2001; Bud'ko et al., 2001).

In the summer of 2001, two independent studies were published (Osborn et al., 2001; Yıldırım et al., 2001). In one of the studies, Osborn and his group reported inelastic neutron scattering measurements of phonon density of states on an isotopically enriched polycrystalline sample of $Mg^{11}B_2$ prepared at Argonne National Laboratory (Osborn et al., 2001). This study determined the lattice vibration energies and allowed them to conclude that superconductivity is consistent with a conventional phonon mechanism with moderately strong electron-phonon coupling.

The other study was conducted by a collaboration led by Jeff Lynn and Taner Yıldırım of National Institute of Standards and Technology in Gaitherburg confirms the Argonne group's neutron scattering results and proposes a more detailed analysis using a model of MgB₂ based on the fundamental laws of superconductivity (Brumfiel, 2001).

According to the study, there are four phonon modes in the zone center, three of this mode are harmonic up to $u/a \approx 0.065$ (u is magnitude of the displacement of ions with phonon vibration and *a* is the lattice constant) one of them is very inharmonic. They calculated an insignificant coupling for three harmonic modes and concluded that electron-phonon coupling is negligible for these modes. However, for the inharmonic mode, the coupling is large indicating significant non-linear electron phonon coupling. In this mode, the boron ions vibrate in opposite directions. After the calculation, they infer that MgB₂ is a conventional electron-phonon superconductor in the strong regime and the conducting electrons form pairs by connecting to each other via specific lattice vibrations. (Yıldırım et al., 2001) The pair formation can be simply explained with regard to inharmonic mode. In this mode, boron ions vibrate in opposite directions along *x* (or *y*) axis, with the Mg ions stationary, when two boron atoms become close enough electrons are let to jump between them. As a consequence of the correlation between lattice vibrations and electrons cooper pairs and enormous vibrations are formed. (Yıldırım et al., 2001; Brumfiel, 2001)

After the detailed theoretical studies given above the material properties, the strong coupling formalism of superconductivity, and the reproduction of superconducting transition temperature of MgB_2 become possible (Choi et al., 2002).

1.5 The Objective of This Thesis

Concerning the brittle structure and interruption of the superconducting phases by cracks, the widespread use of MgB₂ in applications becomes possible with increasing the ductility of MgB₂ by use of malleable metals. One way for rendering MgB₂ with improved mechanical properties is the production of composites as previously touched on. The melting point of MgB₂ is 1073 K and decomposition temperature is above that value. (Sharoni et al., 2001) To form composites, one should select a metal with lower melting temperature. MgB₂ composites with Al, Mg and Zn were fabricated and found that their transition temperature by an amount of 2 K, it is still much higher than existing conventional superconductors. Among these three metals, composites synthesized by Mg have highest critical current density, $5.6 \times 10^5 \pm 5.6 \times 10^4$ A/cm² (Dunand a).

In this study, we have chosen Mg among the candidate materials to fabricate metal matrix composites of MgB₂. The reason for this choice is that Mg undergoes no reaction

with MgB₂ and has relatively low melting point. Furthermore, excess Mg might help MgB₂ to keep stoichiometry. The commercially available MgB₂ powders (98% pure) manufactured by Alfa-Aesar are used in the fabrication of Mg/MgB₂ metal matrix alloys. To measure the T_c of Mg/MgB₂ metal matrix composites, we have performed standard four-probe dc resistivity method. In addition, structural characterization has been made by X-Ray Diffraction and Energy Dispersive Spectroscopy (EDX).

CHAPTER 2

THE CRYSTAL STRUCTURE OF MgB₂ AND PREPARATION OF BULK SAMPLES

2.1 The Crystal Structure

The existence of MgB_2 was first revealed at early 1950's but superconducting behavior of it first observed in 2001. As mentioned in the first chapter, the metallic conventional superconductors have many advantages compared T_c to high temperature superconductor cuprates and the discovery was striking because MgB_2 was almost doubling Nb₃Ge in transition temperature. Before MgB₂ the highest T_c among binary metallic compounds was just 23 K, which is the transition temperature of Nb₃Ge.



Figure 2.1 The structure of MgB₂ (Larbalestier et al., 2001)

The structure MgB₂ suits that of simple hexagonal A₁B₂-Type materials. Closepacked layers of magnesium are sandwiched between honeycombs like boron layers. As seen in the Figure 2.1 magnesium atoms are located at the midpoint of boron hexagons. The lattice constants *a* and *c* of MgB₂ change with the starting composition of Mg and B. With different starting compositions the values of *a* and *c* become 3.0855 ± 0.0006 A° and 3.522 ± 0.002 A°, respectively. Since variations in the values of *c* are larger than the statistical errors and probably caused by random instrumental errors, in the study these were partially overwhelmed by simply taking c/a ratio. In average c/a is equal to 1.1414 and since the changes in the *c* values 3.5 time greater than that of *a*, c/a mainly shows the change in the *c* axis.

The results obtained from the calculations made on the band structure of MgB_2 give signs of the substantial ionization of Mg by wholly transferring the electrons founding 3s orbital to 2 dimensional boron sheets (Kortus et al., 2001; Buzea et al., 2001). Hence, ionic Mg-B bonds and covalent B-B bonds forms the hexagonal structure of MgB₂ (Kortus et al.; 2001; Tampari et al., 2002). As a result of the anisotropy in the bond lengths between boron ions found in the same plane and neighboring planes, boron ions in MgB₂ gain very similar structure to that of graphite. 2 p boron states have metallic character and determine the density of states at the Fermi energy, E_f, which are energy of the highest occupied states at the ground state of a system (An et al., 2001). The Fermi surfaces of MgB₂ comprise two sheets from the σ -bonding states of boron $p_{x,y}$ orbitals and two sheets from the π -bonding states of boron p_z orbitals. The σ -bonding states at the Fermi level derived from boron $p_{x,y}$ orbital are confined in the boron planes (Choi et al., 2002b). The bands near Fermi level and superconductivity arise mainly from $2p_{xy}\sigma$ bonding orbital of boron (An et al., 2001). Contrary to the graphite, the σ bonding states in this structure are partially occupied and the charge in the σ -bonding states are not distributed symmetrically relative to the in plane position of the boron atoms (Choi et al, 2002b, T. Yıldırım et al., 2001). In consequence, like in the case of HTSCs, MgB₂ is a holes-based superconductor (Kang et al., 2001). The unsymmetrical charge distribution in the σ -bonding states leads the only strong coupling in the Fermi level and so strong electron-pair formation. In comparison with σ -bonding states, the π bonding states form much weaker pairs. The main contribution to superconductivity comes from the pair formation resulting from the strong-coupled σ -bonding states, confined to the boron planes (Choi et al., 2002b). Contribution of Mg-B ionic bond to the superconductivity is not noticeable (T. Yıldırım et al., 2001). While electron pair formation of σ -bonding states posses an average energy gap $\Delta = 6.8$ meV that of the π bonding states has only an average 1.8 meV (Choi et al, 2002b).

Result of calculations performed according to Eliashberg formalism suggests that superconducting energy gap of MgB_2 has s-wave symmetry. In s-wave symmetry, even the size of the gap can change drastically on the different parts of the plane, the gap takes non-zero values and posses the same sign everywhere on the Fermi surface. Notwithstanding conflicting experimental results about the number of gaps in the MgB₂, the two-gap structure and their values obtained from the theoretical calculation of Δ by Eliasenberg formalism is confirmed with the recent experiments (Choi et al., 2002b).

The isotope-effect (the effect of change in the phonon vibrations and so T_c due to the different masses of isotopes) coefficient is large for B but quite small for Mg (Hinks et al., 2001, An et al., 2001) with the reduced total coefficient of 0.32 (Hinks et al., 2001). Evidence for a multi-component gap has been obtained from measurements of the specific heat, whose temperature and field dependence are substantially different from that of isotropic s-wave superconductors (T. Yıldırım et al., 2001). The emerging picture is that MgB₂ has properties resembling that of photon-mediated BCS type conventional superconductor with a more complex nature than existing ones.

There are several attempts to obtain nonstoichiometric compositions of MgB₂. Only a few try leads to significant substitutions on the either sites. While in many studies nonstoichiometry is speculated as explanation of variation in the different samples prepared at the same synthesis temperature with a range of composition, it is revealed that MgB₂ is a line compound (Ribeiro et al., 2002). In the study, Mg_xB₂ was produced by different starting compositions ranging between x = 0.6 and x = 1.3. According to this study excess Mg exist as an impurity phase in Mg rich region. The researchers hypothesized that some of the Mg is situated on the grain boundaries. For higher concentrations of Mg than that in Mg_{1.1}B₂, Mg leads to relieve of the interaction among the randomly oriented MgB₂ crystals. When composition is in between Mg_{0.9}B₂ and Mg_{1.1}B₂, the amount of Mg metal or MgB₄ impurities are not significant to dominate the behavior of the lattice and it is mainly determined by grain interaction stresses among the randomly oriented MgB_2 crystals. When x is less than 0.9 the concentration of MgB4 impurity phase becomes important in the behavior of the material. In that case the response of the lattice and peak broadening parameters influenced by both MgB₂ and MgB4, and they behave as MgB2/MgB4 composites. At the end of the study the researchers conclude that with the given range of starting composition nonstoichiometry is possible with a maximum 1% Mg vacancy in the MgB₂ structure, the other variations of the composition lead impurity formations in the material. Furthermore they also claim that the behavior of T_c determined by the impurities in the Mg and B. The accidental impurities in the sample caused by Mg and B can be used to provide

deliberate chemical substitutions like use of BC as starting material to synthesize C-doped MgB_{2-x}C_x (Ribeiro et al., 2002; Hinks et al., 2002).

In the following part XRD analysis of the materials used in our experiments are given. Figure 2.2 shows XRD analysis belongs to the commercially available Alfa Aesar MgB₂ powders and the Figure 2.3 belongs to the Mg powder. Although they are not denoted in the XRD graph due to their weak peaks search match results indicate that small amounts of MgB₄ and MgB₆ phases can exist in the commercially obtained powder.



Figure 2.2 XRD Pattern of Commercial MgB₂



Figure 2.3 XRD Pattern of Mg powder

Mechanical properties of pure MgB₂ are very poor for application. As a result of this, extensive research has been conducted to increase malleability and ductility of the MgB₂. To introduce such properties, one method is the production of tapes, wires or ribbons by use of a metal sheaths and another one is fabrication of composites. There are many factors affecting the superconducting and mechanical properties of MgB₂ samples, so the techniques used in the preparation of bulk samples are very important and need to be more closely examined.

2.2 Preparation of Bulk Samples

Although there are many methods to obtain MgB_2 , all of them mainly based on the solid-state reaction of B and Mg atoms. The following reaction represents such a formation of MgB_2 .

$$2B+Mg \xrightarrow{\text{Sintering at 900 °C}} MgB_2$$

There are many factors affecting the quality and cost of the resultant MgB₂. Evidently approach followed in production and the quality of initial B and Mg are some of the most important points among them.

To obtain MgB₂ by the solid-state reaction, initial stoichometry of Mg and B is not necessary. Starting composition ratio of Mg and B is a factor that alters superconducting properties (Hinks et al., 2002). Even initial nonstoichometric composition can leads better results (Schlacher et al., 2002). On the other hand, the role of it less than the purity of the initial powders purity (Hinks et al., 2002). One of the major factors affecting the residual resistivity ratio (RRR= ρ (300 K)/ ρ (40 K)) and ρ_o values of MgB₂ is the purity of the B powders. Especially initial boron powder impurity may result in RRR values as low as 4 and high purity cause RRR values of more than 20 with a residual resistivity 0.4 μ Ω cm. In addition, T_c values slightly increases with increasing purity of B powder (Ribeiro et al., 2002). Non-stoichometry is possible with 1% Mg vacancy in MgB₂ excess Mg and MgB₄ is included in the structure as impurity phases (Hinks et al., 2002). T_c decreases slightly in the Mg reach region and no considerable change in the deficient side. This may be result from impurities in Mg. In another study it is claimed that Mg deficiency cause a decrease in T_c as much as 3 K with x= 0.5 at Mg_xB₂ (Zhao et al., 2001).

Modern practical superconductors are required to exhibit a wide range of properties. To meet these needs a somewhat specialized group of composites with their accompanying fabrication techniques have been innovated. Besides the best properties possessed by the ingredients, the composites even exhibit some extra properties not attainable by neither of them. Although there is no absolute definition given by an authority more applicable one is that composites are materials containing a mixture of two or more types of fundamentally different components one of which acting as a matrix (or binder) material completely surrounding the other constituents, namely reinforcements. The combining of two or more materials is done by physical means and have distinctive component properties, in other words the components are generally mechanically separable and not lose their identity as opposed to chemical bonding occurring in the alloys of monolithic solid materials. In composites mixing occur in macroscopic scale not in atomic scale.

The types of reinforcements used in composites have different effects on the characteristics of the composites. Reinforcements are usually found in the form of fibers, particles or whiskers in the matrix materials. Whiskers are elongated single crystal particles with a definite width-to-length ratio less than one and significantly improved properties. A prior property of the fibers is having one very long axis compared to the others, which are often circular or near circular. While whiskers lengths typically range between 2-50 nm that of fibers are much larger than these values. Some of the whiskers are preferred in ceramic or metal matrix according their capacity to withstanding temperature as high as 2000 °C and some others are used in place of fibers for a better process. Because of additional effort needed to bring on composites including whiskers with desired configuration and their cost, practical uses of them are limited. In the literature, there is a study of microstructure of in-situ formed MgB₂ phases in a hybrid Mg alloy matrix composites reinforced with SiC whiskers and B₄C particles (Chen et al., 2002). In this study MgB₂ are in-situ formed by the following chemical procedure: $B_4C+O_2 \rightarrow B_2O_3+CO_2$, $B_2O_3+Mg \rightarrow MgB_2+MgO$. As a result of reaction the MgB₂ faces obtained with SiC reinforcements. In the structure another benefit of B₄C particles additional to behaving as boron source for MgB₂ is that they attempt to separate the SiC whiskers uniformly in the composite. Today most of the superconductors in use, are composites. The composites based on the low T_c materials, NbTi, Nb₃Sn, Nb₃Ge.

Since, we need to improve mechanical and electrical properties of MgB₂, the metal matrix composites (MMCs) is proper choice and naturally preferred to the other five classes of composites, namely polymer matrix composites (PMC), fiber reinforced plastics (FRP), ceramic matrix composites (CMC), fiber glasses and advanced fiber composites. Due to the subject of this thesis, I will explain only MMC and skip the later five. Numerous fabrication techniques exist for MMCs. Among the candidates two methods namely powder blending and consolidation, and squeeze casting and squeeze infiltration, are main applied methods for the production of the metal/MgB₂ composites.

Powder blending and consolidation:

Powder blending and consolidation method is a commonly used method for the preparation of discontinuously reinforced MMCs. Powders of the metallic matrix and reinforcement are first blended and fed into a mold of the desired shape and subsequent to these processes consolidation is performed either by uniaxial hot pressing (UHP) or hot isostatic pressing (HIP) (DDA, 1999; Giunchi et al., 2002). Even by use of these techniques high pressure prevents the decomposition of the MgB₂, unfortunately the use of both HIP and UHP bring some limitations due to the practical difficulty in the use of very large vessels and dyes, when high pressure and high temperatures are involved (Giunchi et al., 2002).

Squeeze casting and squeeze infiltration:

Pressure infiltration, which promotes wetting of fibers by matrix and reduces porosity, is often called squeeze casting. Porous preforms of reinforcement material are infiltrated by molten metal under pressure to produce metal matrix composites. Composites can be made by infiltrating liquid metal into a fabric or prearranged fibrous configuration called a preform. Frequently, ceramic or organic binder materials are used to hold the fibers in position. The latter is burned off before or during infiltration. Infiltration can be carried out under vacuum, pressure, or both. It is shown that obtaining high density and high quality MgB₂ pellets is possible with liquid infiltration technique (Giunchi et al., 2002). In the study porous body of B powders (performs) is infiltrated with liquid magnesium and densification made possible only by use of metallic container without the standard way of consolidation techniques applied in powder blending method. The inner walls of the container counteract the pressure by the expansion of the MgB₂ forming phase and leads formation of a dense structure. Even in the study one of the best J_c and applied magnetic field relation obtained for bulk MgB₂, when compared to the other superconducting materials it is revealed that further improvements such as better flux pinning mechanism improvement is necessary to compete with them (Giunchi et al., 2002).

For MMCs several aspects such as forms and types of the matrix and the reinforcement materials should be take in to consideration to obtain suitable composites for specific applications. Properties of different type of matrix materials like electrical resistance, melting temperature and strength can dramatically affect the end product characteristics.

A common method to study the factor affecting the properties and improve MgB_2 for several applications a common method is the fabrication of pellets. To develop a commercial or technologically applicable product many tries are required. Fabrication of pellets provides cost effective and easy method to test several factors. The other objective behind the production of pellets can be summarized as follows:

- By formation of pellets, it is more become to use measurement methods like four probe technique which will be mentioned in the following chapter of this thesis.
- It becomes possible to study effects of several factors easily in a small volume.
- If the pellets are formed to synthesis MgB₂, pressure can enhance the formation of MgB₂ by decreasing the distance between Mg and B powders.
- Increasing grain connectivity: The applied pressure to form pellets decrease distance between grains. If this distance is larger than the coherence length weak link problems occur.

However in practice superconductors generally are not used in the form of pellets. In addition to the requirement for higher values of T_c , H_c and J_c for a superconductor, from the manufacturing point of view these products must be capable of being economically fabricated with relative ease in to long lengths and with properties, which are invariant along the composites. To perform such a long length superconductors, wires and tapes are produced by cladding of the superconductor materials. The cladding materials need to have high thermal and electrical properties because they provide parallel electrical conduction and thermal stabilization.

2.3 Powder In Tube Method

To produce wire and tapes most applied method is powder in tube (PIT) technique. Wires and tapes should be malleable. To increase this property of commercially available MgB₂, stoichiometric or near stoichiometric rates of Mg and B are inserted in to metal clad. PIT method consists in the following procedure:

- •MgB₂ reacted powder or a mixture of Mg and B powders packed in various metal tubes or sheaths.
- •These tubes are drawn into wires as seen in Fig. 2.4, cold-worked into ribbons, if in-situ formation is preferred a heat treatment around 950 °C is required for the

formation of MgB₂. Otherwise followed by optional a heat treatment at 900-1000 $^{\circ}$ C



Figure 2.4 A Simple Demonstration of Powder in Tube Method

To fabricate multi-filamentary cables many of this filaments brings together by bundling and further drawing and rolling. The Fig. 2.5 is a cross section of a HTS tape. From top to bottom magnification is increased. The darker parts correspond to superconducting materials, light parts are Ag sheaths. In this structure, the single filaments of superconductors are brought together to form small-cylindrical bundles, then by repeating application of PIT methods the larger bundles were obtained. The application of this method three times, the tape cross-section given at the top of the picture is obtained.

Because of strong chemical reactivity of MgB₂ the choice of proper metal cladding is a critical point. If sintering is required, many metals, which have low melting points, should be excluded. Even many become useless during the sintering of MgB₂ around 900-1000 °C due to the tendency of Mg in MgB₂ to react and combine with many metals by forming solid solutions or intermetallics by lowering the melting points. On the other hand, many inert refractory metals such as Mo, Nb, V, W and Hf are not ductile and malleable enough. As a result of these, only a few materials appeared to be appropriate to use cladding such as Fe, stainless steel and Ti (Jin et al., 2001). Hardness of the core is correlated to sheath materials. The harder the sheath material are used, the harder core obtained (Matsumoto et al., 2002; Kitaguchi et al., 2001).



Figure 2.5 The cross-sections of high-temperature superconducting wires (Tallon, 2001)

There are many other factors affecting the performance of the tapes, wires and cables produced by PIT techniques. Each technique leads different microstructural and superconducting properties. A brief summary of the factors affecting superconducting properties take part in the literature is given in the following sections of this chapter.

In an issue, the powder-in-tube process is applied to obtain stainless-steel ribbons, and for sintering and non-sintered ribbons T_c (onset) values are found as 38.5 and 36 K, respectively. These samples have a sharp superconducting transition. Even the sintering ones have 2.5 K higher transition than that of no-sintering ones, still they have sharper transition and higher T_c than these of pallets fabricated under 3 GPa (Jung et al., 2001) with commercially available MgB₂ powder without any heat treatment. The improved properties the non-sintered ribbons compared to the pellets can result from swaging and rolling of the tubes (Song et al., 2002).

In-situ and ex-situ formed MgB₂ wire show different properties. Even though it seems that most outstanding method is the ex-situ fabrication of wire with commercially available homogenous MgB₂ without any substitutions, the better critical current densities can be obtained by in-situ formation of MgB₂ (Schlacher et al., 2002). In double heat treated with Fe cladding MgB₂ wires, non-stoichemetric Mg:B precursor ratio of 0.9:2 shows the best J_c values for both ex-situ and in-situ wires with 0.7:2 up to 1.3:2 formed wires. Contrary to this, best T_c values are obtained with loosely packet commercial powder in a sample holder and T_c values of heat-treated in-situ formed MgB₂ wires. For both type of the wires, the heat treatment cause an increases in J_c and T_c (not much than 40 K) values. In the study, better J_c values of non-stoichometric MgB₂ wire is explained by presence of good percolation paths with Mg precursor sides suppose to contain more Mg than that required for MgB₂ formation. These parts are situated between the boron rich grains through with little amount of Mg penetrate by dendrite like cracks.

In in-situ fabrication process, the losses of the Mg near the cladding zones must be considered. For example, large solubility of Mg in silver leads wires with rather porous core with decreased superconducting properties (Matienez et al., 2002). After the most of the Mg is alloyed with Ag, only small amount is available to react with boron. However, this is not the case for Cu cladded wires. Formation of thin MgCu₂ layer around the superconducting core prevents the further losses of Mg (Matienez et al, 2002; Zhou et al., 2002). The Mg rate in the end product is also affected by the core sheath interface surface versus the core volume, temperature of annealing and annealing time. At the end of the experiment made by Ag, Cu and Fe sheets, it is revealed that as the heat treatment temperature is increased from 600 to 700 °C, the critical current density of Ag sheeted tapes remains constant. Above 700 °C up to 800 °C it decreases continuously and at 800 °C J_c vanishes. For Cu sheeted tape, J_c increases and the best J_c values achieved around 800 °C, than J_c begin to decrease and vanish at 850 °C. Fe cladding gives the same J_c values between 600 and 700 °C. Above 800 °C in contrast to the Cu-sheathed tapes the J_c value continues to increase. In the temperature range between 600-800 °C although the most pure MgB₂ phase is formed in the Fe sheated tapes, the J_c values are higher in the Cu-sheathed ones. Even both a larger amount of impurity phases makes the effective area of the superconducting core cross-section smaller and more percolating supercurrent flow which may cause a decrease in J_c values, in the given temperature range increase of J_c value may be a result of vortex

pinning enhancement of impurity phases (Zhou et al., 2002). Above the given temperature range the critical current densities in Fe sheathed wires continuous to increase while that for Cu sheathed ones decreases because of reactions (Zhou et al., 2002). Short sintering causes less reaction between sheath and MgB₂ and can increases the J_c values of Cu and Ag sheathed wires. On the other hand, still Fe gives better results (Soltaian et al., 2002). When Fe used between Cu clad and MgB₂ as buffer layer, it prevents the reaction of Cu with the core at higher temperatures. Even after sintering about 900 °C, well-defined Cu and Fe clad was distinguishable from the core. In studies conducted with stainless steel and Cu-Ni tubes with Cu-10 wt % Ni without heat treatment result in better J_c values for stainless steel cladding due to the higher packing density of MgB₂.

Mechanical deformation from round wire to flat tape sample under 620 $^{\circ}$ C also has different effects on the J_c when Ag, Cu and Fe cladding is used. Best results are obtained with Cu cladding is a sign of that with Fe cladding optimal density of core achieved by small deformations. In addition hardness of Fe prevents huge deformation, since it breaks. Ag sheathing also shows a poor performance in this case (Zhou et al., 2002)

Filling factor is another important factor. Wires and tapes fabricated by lower filling factor are expected to show higher J_c values (Suo et al., 2002; Grasso et al., 2001) For example it is shown that a decrease in this factor leads better Jc values (Grasso et al., 2001). Further enhancement of both critical field and irreversibility field is possible by a reduction in grain sizes. When the grain size is large tight packing of grains become difficult compared to the MgB₂ tapes and wires obtained by using fine powder. Also the grain size may affect the pinning properties. (Beneduce et al., 2002; Zhoa et al., 2002a). However, the upper critical field remained unchanged (Beneduce et al, 2002). On the other hand, the procedure used for obtained finer grains strongly affects the results. In this process, the impurities can be added to the structure or oxygen absorption can occur by grains because of having large effective surface area of grains compared to their volumes. The resulting J_c values may decrease or increase (Suo et al., 2002; Zhoa et al., 2002a). Moreover the grain size can also be decrease by some dopant like Zr and Ti addition of this material decrease the growth rate of MgB₂ grain (Zhoa et al., 2002a). In MgB₂/Fe tapes, mono-filamentary ones give better J_c values than multi-filamentary ones. This may result from intermediate annealing applied in multi-filamentary tape fabrication (Suo et al., 2002) and poor grain connectivity.

In practice, the power transmission cables must preserve their superconducting properties when subject to large strain and stress. It is shown that MgB_2 /stainless steel conductors have a large possibility to be used in practice. They have critical strain almost doubling that of Bi-2223/Ag tape. Here critical strain represents the strain where rapid decrease of critical current density (J_c) occurs (Kitaguchi et al., 2001).

To further improve the J_c in the wires and tapes, the grain linkage and presence of pinning centers are other points, which need to be taking into care. Fabrication of the core/sheath composites is a way to increase linkage between the grains. In this method, PIT technique in the previously mentioned studies employed by addition of metal powders to MgB₂ to form the core of tape or wire. After several attempts done with Ni, Cu, Ag, In and Sn (Tachikawa et al., 2002a) it is revealed that presence of soft metals with low melting points such as Tn and Sn enhance the critical current when compared with the samples produced without any addition of them. Also Ag addition leads slight positive effect. On the other hand, the addition of Cu results a significant decrease in J_c of the tapes. Similarly Ni also decreases J_c but this result is interpreted as depending upon the decrease in the effective path.

As previously mentioned grain size is an important parameter. In addition to drawing, rolling and high pressure applications, addition of some impurities in synthesis stage of MgB₂ like Zr and Ti at ambient pressure also lead a reduction in grain size (Zhoa et al., 2002a). Zr and Ti prevent the large grain growths and form a very thin layer of TiB₂ and ZrB₂ around the grains. While without addition of these materials, the large grain sizes lead to a decrease in effective surface area which may be important pinning centers and existent impurities between the grains may reduce the grain connectivity. After doping with Zr and Ti, the resultant small grain sizes of MgB₂ and similarity between the crystal structures of MgB₂ and TiB₂ or ZrB₂ leads extremely tight packing by preventing formation of phases with different crystal structure like MgB₄ (Zhoa et al., 2002a).

Tight packing of grains and factor of Ti in increasing pinning effects also anticipated by another report with the samples prepared under ambient pressure with Ti doping highly dense and good performed bulk materials under various magnetic strength has achieved (Zhoa et al., 2001).

The samples obtained with these techniques denser than that synthesis under several GPa (Zhoa et al., 2002). In addition, Ti doping increases the J_c values of the samples

with respect to pure ones. On the other, hand it degrades faster by the increasing applied field above the 10 Oe (Zhoa et al., 2001).

In view of obtaining higher upper critical fields than pure substance, improvement of such characteristics through structural or microstructural modifications becomes important. In this manner, the substitutions and doping of MgB₂ with other materials also form research area which should be take in to consideration and may be employed to obtain well tailored MgB₂ superconductors for different purposes. Most of the experimental studies performed to observe the effects of different substitutions and dopants are experienced by fabrication of pellets.

2.4 Effect of Substitutions on Superconducting Properties of MgB₂

Addition of other materials not always ends with the substitutions to MgB₂ structure. The significant substitutions only have been achieved for a few substances and after some optimum amount phase transitions and strong degradation of superconducting properties observed. The solubility limits of various substances have been reported in the literature and in these studies there is no case other than one exception where chemical substitution has increased the Tc above the value given for pure MgB₂ (Hinks et al. 2002; Moritomo and Xu, 2001). On the other hand, in a theoretical study effects of C and Cu substitutions in MgB₂ are searched and it is estimated that replacement of Mg by Cu and low C substitution in the B sheathes can increase the T_c of MgB₂ (Mehl et al., 2001). In a series of study made with Mg_{1-x}Li_xB₂, Mg_{1-x}Cu_xB₂, Mg_{0.95}Cu_{0.05}B_{2-x}C_x and Mg_{0.80}Li_{0.20}B_{2-x}C_x indicates that T_c remains almost constant with increase in hole concentration and decrease with increasing electron concentration. If general formula of this compound is stated as Mg_{1-y}M_yB_{2-x}C_x where M=Li, Cu, this structure is electron doped in the case of x-y>0 and x-y<0 for hole doped case (Balaselvi et al., 2002).

While the studies are in an agreement for the contraction in parameter *a* by substitution of MgB₂ by Li, there are contradictory results claiming decreasing (Li et al., 2001) and constant values (Zha et al., 2001) for parameter *c*. Na substitution leads and increases both *a* and *c* values, on the other hand higher concentration decreases these parameters. T_c slightly decreases with Li substitutions (≈ 0.6 K) when x exceeds 0.5 in Mg_{1-x}Li_xB₂ the material losses superconducting properties (Cimberle et al., 2001; Li et al., 2001). Presence of small amount of Li enhances the J_c

(Cimberle et al., 2001). For Na substitutions there is no apparent change of T_c (Zha et al., 2001).

A significant suppression occurs in T_c values as a result of Mn substitutions to the MgB₂. Al also decreases T_c but less than Mn for small doping levels. For example while at x = 0.05 the Mg_{1-x}Mn_xB₂ structure take a T_c value around 30 K (Xu et al., 2001) in the same range of x for Al substitution T_c onset is obtained around 37.2 K (Cimberle et al., 2001; Slusky et al, 2001). Presence of small amount of Al can also enhance J_c (Cimberle et al., 2001). Change in T_c interpreted as result of reduction in density of states at Fermi level N(E_F) (Kotegawal et al., 2002). Increasing Mn and Al substitutions leads further decrease in the values (Xu et al., 2001; Dong et al., 2001). Moreover with more Al addition phase transitions have been observed at the 17% and 75% doping levels. 50% doping leads a MgAlB₄ structure with a transition temperature about 12 K (Dong et al., 2001). Solubility of substituents is a factor need to be considered. As in the case of Al dopants beyond some concentration materials can form other structures in place of substituting in structure of MgB₂. Doping MgB₂ with Cu is a difficult task. The reason of this is the high affinity of Mg and Cu to form cubic inter metallic compounds with a Cu/Mg ratio ranging from 2/3 to 3. As a result of this attempts to synthesize of solid solutions Mg_{1-x}Cu_xB₂ with Cu were not successful and these solids solutions attained by use of CuB_{24} . Even with this way substitution with ranging from x=0.003 to 0.03 become possible. In this range increase in the substituent concentration results with a nearly 0.5 K degradation in T_c at x=0.03 (Tampieri et al, 2002). Almost 0.4 K decrease occur in the T_c values of Si substituted samples and one of the steepest transition occur with Si substitutions with a $\Delta T = 0.7$ K (Cimberle et al., 2001). Hysteresis loops measured at low temperature indicate an improvement of the critical current density about a factor 3 with the Si doping. Zn also led only sight changes in T_c value in negative direction (Xu et al., 2001). Although it is not confirmed there is only one study assorting that Zn substitution with x = 0.003 result in a T_c increase around 0.2 K and decreases in the other studies explained by presence of excess Zn over the optimum dose around x=0.004 (Moritomo and Xu, 2001). Superconducting state of MgB_2 is amenable to the spin impurity (Xu et al., 2001).

It was suggested that Ta powder addition to the starting composition of B and Mg leads an increases of critical current densities. The presence of Ta foil around the tablet samples also an enhancing factor of J_c (Prikha et al., 2002).

As a result of mixing of 5 mole % each of fine particles of Fe, Mo, Cu, Ag, Ti and Y with as received MgB₂ powders in clad metal and heat treatment around 900 °C it was showed that presence of this particles have only little effect on the T_c of MgB₂. Due to the mutual solubility of Y with Mg and reactivity with B, some broadening of transition was observed. On the other hand J_c studies revealed that J_c could be significantly reduced. While Fe addition appeared to be least damaging Cu addition can significantly reduce that value on the 2-3 orders of magnitude. The addition of other metals takes values between these, two materials. This behavior can be attributed to the formation of reacted layers around the grain boundaries. While Ag, Y and Ti can react with both Mg and B, Cu can react with Mg and Fe and Mo react with boron. The presence of such layer can cause weak link problems (Jin et al., 2001).

It is theoretically predicted that Be substitution for B is unfavorable (Mehl et al., 2001). The solubility of carbon in boron is probably less than 2.5 % and the presence of carbon is detrimental to the superconductive properties of MgB₂ samples (Paranthaman et al., 2001). Experiment with MgB_{1.8}C_{0.2} pellets leads two distinct onset temperatures one at 41 K the other is at 37 K and compared with MgB₂ transition width of this samples are very broad. Also with this composition single phase of material obtained with smaller B-B bond and only small amount of MgO impurities (Ahn and Choi, 2001).

There are only a few studies directly related with effect of excess Mg and Mg/MgB₂ composite fabrication. One of them is a microstructural study of in-situ formed MgB₂ phases in a Mg alloy matrix composites reinforced with SiC whiskers and B₄C particles without any attribution to superconducting and mechanical properties of the resultant products (Chen et al., 2002). Mg/MgB₂ composites produced by liquid infiltration technique, in which pure Mg infiltrated in to the tapped commercial MgB₂ powder perform, found to have high density and transition around 38K with much larger transition than pure samples MgB₂ prepared by this group. In another method followed by same group had showed the possible synthesis of MgB₂ by the liquid infiltration of B perform with Mg possessing a transition around 37 K. Further annealing of this samples results a superconducting transition around 39 K with very brittle structure and pure mechanical properties (Dunand et al., 2001). In another report effect of unreacted Mg in MgB₂ was given as broadening of transition temperature and increasing the RRR (ρ (300 K)/ ρ (40 K)) values (Jung et al., 2002b). Despite these results it was also claimed

that small amount of excess Mg slightly increases T_c with respect to that of commercially available MgB₂ (Jin et al, 2001).

2.5 Effect of Pressure

The response of transition of MgB_2 is negative to the highest pressure studied in literature. An interesting point in the studies is that samples with lower T_c at zero pressure have much steeper $T_c(P)$ dependence than the samples with higher T_c . In addition to these, the lattice parameter along the c axis decreases faster with pressure than along the a-axis. This implies that the out of plane Mg-B bonds are much weaker than in plane Mg-Mg bonds (Buzea and Yamashita, 2001).

Regardless of the negative effect on the T_c , production of MgB₂ under high pressure seems to be very promising because of the resultant highly dense structures. Samples with a 95-97 % of the theoretical density were achieved with both pressure and heat treatment (Prikha et al., 2002). Since the grain connection in denser structures are more than porous ones pressure affect the J_c in a positive manner. Even the hot isostatically pressing of commercially available MgB₂ around 950 °C and 100 MPa leads 2 K decrease in the T_c 100% dense samples with superconducting homogeneity are obtained (Shields et al., 2002). The density of samples was measured as 2.63±0.02 g.cm⁻³ which is very close to the theoretical density of 2.625 g.cm⁻³ (Indrakanti et al., 2001).

Although the application of pressure increase grain connectivity, decrease the decomposition during the sintering and aid to obtain denser structures, practical use in large dimensions are limited as previously mentioned. However it is possible to attain large bulk manufacts in an inexpensive way with liquid infiltration technique, without need of high-pressure apparatus (Giunchi et al., 2002).

In addition, since the stress introduced among the grain boundaries do not relieve, stress effect could be greatly amplified in the samples made at a high pressure (Ribeiro et al., 2002, Hinks et al., 2002).

2.6 Effect of Sintering

A large increase of J_c is observed in many studies of with annealing of samples. If annealing is performed in the presence of the other materials like in PIT or in fabrication of composites, this enhancing factor depends strongly on the melting temperature and reactivity of these materials with the MgB₂. J_c can increase with increasing temperature for a while and after some temperature like in the case of Cu (Zhou et al., 2002) and stainless steel (Matsumoto et al., 2002) sheathed wire and tapes it tend to decrease. In addition, the synthesis of MgB₂ in contact with BN results in similar picture of the J_c values around 950 °C (Prikha et al., 2002). If the materials are not reactive as in the case of Fe increasing trend of J_c also valid for higher temperature needed to attain a well behaving MgB₂ (Zhou et al., 2002; Matsumoto et al., 2002).

The improvements in the J_c values mainly depend on the linkage of MgB₂ grains. In Fig. 2.6, SEM pictures demonstrates effect of increasing sintering temperatures on the samples prepared with same composition and with same pressure. It is apparent that higher sintering temperature results with better grain connectivity and less porous structures.



Figure 2.6 SEM images reflecting effect of sintering (Jung et al., 2001)

When high temperatures are attained, loss of Mg in vapor form is needed to take in to care especially when in in-situ production of MgB₂ will be employed. While the weight loss during the sintering of ribbons at 900 °C in argon atmosphere was only about 0.8% after same sintering condition around 31% lost of weight was observed. The weight loosed in the pellets almost equivalent to 60% loss of Mg (Jin et al., 2001). With such a heat treatment of pellets no more benefit of sintering is observed because of having highly porous structure (Jin et al., 2001; Slusky et al., 2001).

As in the case of pressure applications the lattice parameter along the c axis decreases faster with temperature than along the a-axis (Buzea and Yamashita, 2001).

Figure 2.6 illustrates the effect of sintering on MgB₂ made under 3 GPa (Jung et al., 2001). The scale bars are 1 μ m in length. The sintering temperatures were a) 20 °C, b) 500 °C, and c) 950 °C. The sample without actual heating, (a), shows well-separated grains with spacious voids. As the sintering temperature is increased, the connectivity of each grain increases and porosity decreases rapidly.

CHAPTER 3

EXPERIMENTAL METHODS

3.1 Sample Preparation

Commercially available 325 mesh powders of MgB₂ obtained from Alfa Aesar and 270 mesh powders (powders 38-53 mic. in diameter) of Mg obtained with a steel file followed by sifting through Retscth D-42759 stainless steel sieves are mixed homogenously. Since the purity of constituents in Mg/MgB₂ MMCs are important in the superconducting properties, at the sifting stages Mg and sieves were very carefully handled to prevent contaminations of Mg. For samples, mixtures of 3 g of MgB₂ and Mg powders of 5%, 10%, 15%, 20% weight ratios of the MgB₂ are prepared for pressing in the form of pellets.

In each time one of these mixtures is inserted in a heat-treated steel dye as depicted in the Fig. 3.1. The dye has inner radius of 7.81 mm and outer radius of 60 mm. After that the dye is placed in heating resistors and Carver 3925 laboratory hydraulic pressure equipment. This equipment has maximum 12-ton pressure capacity. With the aid of these equipments, hot uniaxial pressing carried out with application of 0.5 GPa pressure and heat treatment of about 400 and 500 ° C for 2 hours. After pellet formation was completed, the sample was removed from dye by use of a hollow cylinder and some pressure as shown in Fig. 3.2. During this process temperature control is made by Omega thermocouple system and a variac. As a control group pure MgB₂ pellets of Alfa Aesar powders are also prepared for each sintering temperature.

At the end of these stages, we prepared totally ten samples, 5 for each sintering temperature. The final samples are tablets about 0.9 mm in thick and 15.62 mm in diameter. To measure resistivity, samples are sliced in to bar like pieces. The number of samples, their empirical and theoretical densities and their mutual ratios are given in Table 3.1.



Figure 3.1 Fabrication of Pellets



Figure 3.2 Fabrication of Pellets

Sample Number:	Mg/MgB ₂ Weight Ratio	Temperature of Applied Heat Treatment	Density (x10 ³ kg/m ³)	Theoretical densities (x10 ³ kg/m ³)	Empirical Density /Theoretical density
400	pure	400 °C	1.63	2.625	0.620
405	5%	400 °C	1.7	2.583	0.658
410	10%	400 °C	1.8	2.544	0.707
415	15%	400 °C	1.82	2.509	0.725
420	20%	400 °C	1.92	2.477	0.775
500	pure	500 °C	1.69	2.625	0.644
505	5%	500 °C	1.89	2.583	0.731
510	10%	500 °C	1.98	2.544	0.778
515	15%	500 °C	2.00	2.509	0.797
520	20%	500 °C	2.12	2.477	0.855

Table 3.1 Sa	mple numberii	ng, Mg co	ncentrations,	annealing te	mperatures and	densities.
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3.2 Measurements

At critical temperature, the transition of a material from normal state to superconducting state by acquiring perfect diamagnetism and zero electrical resistance brings about two methods for the determination of critical temperature, namely resistance and magnetic susceptibility measurements. Even the both method serve for this purpose, in this study we had used resistive method. To make measurements, unpolished Mg/MgB₂ composites, fabricated under a pressure of 0.5 GPa were cut in to pieces by diamond-saw with appropriate dimensions. We could not polish the samples because of surface fracturing. The samples were prepared by use of four-point probe technique (Fig. 3.3) to place in cryosystem given in Fig. 3.4.

3.2.1 Four Point Probe Method

Four-point probe method is one of the most widespread methods in the T_c determination. In this study, to make measurement, cupper wires with 0.1 mm in diameter are connected to sample at four points by use of a silver paint as demonstrated in Fig. 3.3. Two of the four contacts on the samples belong to current carrying cables (1 and 4) and the other are attached to the two voltage measuring cables (2 and 3). The reason for the choice of this technique rather than use of two probes is that in the latter one the contact and spreading resistance cannot be separated from measured resistance. On the other hand in the four-point probe method when the current applied from the outer two wires, the voltage measured from the inner probes is not influenced by the resistance at the contact and wires. The inner probes only measure the voltage across the inner probes are known, one can easily determine the resistance of the sample from the Ohm's law. Thermal conductance (between cold head and sample) and stability enhanced by use of vacuum grease.



Figure 3.3 Four Point Probe Method

3.2.2 DC Resistance Measurements

After the preparation of the samples with four-point probe method, we determine the change in the resistance of them with the utilization of computer controlled cryo system of which schematic representation is given in Fig. 3.4. The system provides us a sensitive measurement of resistivity from room temperature down to 12 K.



Figure 3.4 The Cryo System

The system consist of an Oxford Edward Cryostat 1.5 (a closed system helium cryostat), Coolstar Cold Head model 2/9, Keithley 220 current source, Keithley 2000 Digital Multimeter, a water source to cool the Cryodrive, Leybold Trivac Vacuum Pump, ITC 5002 temperature controller, Termovac Sensor with tungsten filament for vacuum measurement, GPIB connectors and IEEE 488.2 interface card for the connection to the computer. The data taken from the system had been processed by an Object Bench program and simultaneously converted to R versus T graph on the screen

as the experiment goes on. To get rid of offset effects in the system, the arithmetic average of absolute value of voltages obtained by changing the polarity of the applied current were taken by the program. Temperature measurements were performed by use of the Rd-Iron Temperature Sensor. ITC 502 Temperature Controller unit with P-I-D control parameters are used to control temperature and Helium flow rates. The data are taken after the achievement of a vacuum medium in the cold head on the order of 10⁻³ Torr. For each samples the resistance measurements were done for 1 mA, 5 mA, 10 mA, 50 mA and 100 mA.

CHAPTER 4

RESULTS AND DISCUSSIONS

To determine superconducting properties of our MgB₂/Mg metal matrix composites, we applied resistivity-temperature measurements, XRD, SEM and EDX methods. In this part, I will mainly mention about the results of these measurements.

To clarify the composition of samples, XRD results are demonstrated in Fig. 4.1 and Fig. 4.2 for 400 and 500 °C heat-treated samples, respectively. As the initial concentration of Mg increases, Mg peaks become clearer. Even no other phases than MgB₂ and Mg are observed in these peaks, examination of XRD results with search match indicates the possible presence of MgB₄, MgB₆ and MgO. Although there are no evident peaks, other impurities found in the initial constituents can exist in these final products in very small amounts. The presence or absence of secondary phases was also examined with EDX. EDX analysis does not lead certain results for the presence of secondary phases, i.e. existence of Mg, B with a weight ratio that suits the MgB₆ stoichiometry not always indicate the presence of MgB₆. In such circumstance, one not able to state the presence of MgB₆ by only relying on the EDX results which can refer the any combination of the Mg, B, MgB₂, MgB₄ and MgB₆. EDX results based on the relative atomic weights and may be misleading especially for light substances or for substances with close atomic weights. On the other hand, the search match results of XRD also confirm the results. Presence of MgO particles may enhance the superconducting properties by acting as pinning center by preventing motion of vortices. On the other hand, the presence of MgB₄ is undesirable, since it is generally situated around grain boundaries with large mismatch in the crystal structures. As a result, the presence of MgB4 causes a loose connection between grain boundaries. Except MgO, the secondary structures are observed in all of our samples and they probably come from commercial powder. MgO concentration might be increased during the heat treatment. Presence of these phases was also detected in the XRD analysis of a similar study on hot isostatically pressed MgB₂ pellets of the same commercially available MgB₂ powders around 900 °C (Shields et al., 2002). Since our temperature range is relatively low for the formation of MgB₄ and MgB₆, and presence of excess Mg prevents the formation of these phases, we do not expect an increase in the concentration of these materials in the samples after the heat treatment. A heat
treatment around 900 °C for pellets leads an enormous weight loss due to the evaporation of Mg (Jin et al., 2001). In our case the temperature that we attained was far from the evaporation point of Mg and enough to soften it under such a pressure. Thus we have not anticipated and observed such a loss of Mg. Moreover from the SEM pictures given in Fig. 4.3 it is revealed that with increasing Mg concentration and temperature porosity decreases. Table 3.1 also indicates a similar result, as temperature and Mg concentration increases the ratio of empirical density to theoretical density increases.

According to SEM images, it looks like that while the grain sizes of MgB₂ is change in the 0.3-5 µm range for 400 °C heat treated samples, that takes values between 0.2 and 5 µm for 500 °C heat treated samples. Even at first glance this impression is gathered from our SEM images, it is hard to state the result with great precision. We have been only able to study unpolished surfaces because of surface contaminations in the polishing process and surface fracturing. The main disadvantages of fracture surface analysis are the presence of many layers on each other with different depths. In such images, observation of actual grain spacing, sizes and distribution of grains and empty spaces is not possible because of the screening by other grains. Grain size refinement generally either observed by drawing and rolling of metal-sheathed tubes (Jin et al., 2001) or addition of some impurities such as Ti and Zr (Zhao et al., 2002). It has been revealed that while short time annealing at 600 °C does not change grain size of MgB₂ in the SUS316 tapes relative to un-annealed ones, formation of reacted regions about 10 µm size in some areas with better linkage enhance the superconducting properties of MgB₂ (Matsumoto et. al., 2002). In other report an increase in the annealing temperature from 900 to 1000 °C (with 30 min duration) for Fe sheathed MgB₂ ribbons fabricated by commercially available MgB₂ powder resulted in about 2.5 times larger grain size (Jin et al., 2001). In our study, we had used commercial Alfa Aesar powders with 325 mesh size. These sizes match with a grains equals to or less than 44 µm in diameter and very large compared to the 0.2 and 5 µm. If these results are right applied heat and pressure for two hour leaded a grain refinement and result in grain size more than 1000 times smaller than that of initial powders. Such a result seems to conflict with the previously mentioned reports. Grain refinement permits consolidations at lower temperatures and increases grain boundary pinning (Zhao et al., 2002).



Figure 4.1 XRD Patterns of Samples Prepared at 400 °C



Figure 4.2 XRD Pattern of Samples Prepared at 500 °C



Figure 4.3 SEM images reflecting effect of heat and excess Mg

The SEM images given in Fig. 4.3 illustrate how the heat treatment and increasing Mg concentration affect the grain connectivity and the porosity of the samples. The left side of the figure includes SEM images of the samples prepared at 400 °C and at other side that of samples sintered at 500 °C are given. A 100 °C increase in annealing temperature results in a consolidation of grains as can be clearly viewed from Fig. 4.3(b) and Fig. 4.3(f). In the figure images are placed in an order of increasing Mg concentrations from top to down. As also confirmed by ratio of theoretical density to empirical one the SEM illustrates that increasing Mg concentration and annealing temperature also decreases voids in the samples.

Fig. 4.4 and Fig. 4.5 demonstrate the distribution of Mg grains in the some of our bulk samples. As can be easily observed from the images Mg does not disperse widely and not diffuse to the grain boundaries. Rather it is present in the form of local clusters. Subsequent to the SEM images, some EDX results suggesting the presence of different phases are given.



Figure 4.4 SEM images of some Mg rich sides in sample 515.

Fig. 4.4 a) demonstrate a Mg rich side in sample 515. Fig. 4.4 b) is a SEM image of the area enclosed by white rectangle. EDX analysis obtained by focusing in the circle gives us a hint about the existence of unreacted Mg. According to EDX result this part is composed of Mg with a weight ratio of 97.64% and small amount of MgO.



Figure 4.5 Mg Distributions in 405&410

EDX of a space of 500 supp be compo MgB ₂ an amount of	a local sample oosed to osed of d .small of MgO.	EDX of space of 500 supp contain I phase.	a local sample oosed to be MgB4	EDX of a local space of sample 505 rich in B and supposed to be contain secondary phases like Mg B ₄ and MgB ₆		EDX of space of 505 supp rich in u Mg conc	a local sample posed to be nreacted centration
Elem	Wt %	Elem	Wt %	Elem	Wt	Elem	Wt
ВK	48.19	ВK	56.07	ВK	73.09	ВK	0.00
O K	6.38	O K	8.81	O K	2.57	O K	0.39
MgK	45.43	MgK	35.13	MgK	24.34	MgK	99.61
Total	100.00	Total	100.00	Total	100.00	Total	100.00

Table 4.1 EDX Results of samples illustrating existence of local places of with different compositions

As previously pointed out in the beginning of the Chapter 4 result given in Table 4.1 can only inform us about the presence of elements and their relative amounts. They do not give which combinations of these elements exist. For example in the first column, weight ratio of B to Mg is very close to the stoichiometric ratio in MgB₂ and this region is supposed to be composed of MgB₂ and small amount of MgO. However this is not an absolute proof for the presence of these compounds, other combinations of Mg and B like unreacted B, Mg or MgB₄, MgB₆ can also be in the region. Considering the initial constituents we can guess that this region mainly consist of MgB₂.

Similar arguments are also valid for the second and third column, in these parts B is much more than that necessary for the stoichiometry. Commercial MgB₂ powder includes secondary phases (MgB₄, MgB₆) in small amounts and these regions are probably includes these phases.

In the fourth column of Table 4.1 the amount of O is not enough to consume all of unreacted Mg to form MgO and obviously EDX analysis of this region denotes existence of unreacted Mg phases in the sample which is necessary for the formation of desired composite structure. Similar analysis was also obtained for the other samples. Since the sintering temperature not high enough to let a reaction of MgB₂ and Mg, this result is not surprising.

4.1 Resistivity Results

The critical temperature is one of the most important basic properties of materials that exhibit superconductivity. There are different determination methods of T_c such as on-set, mid-point, and zero-point (T_c _{zero}). The onset determination is suitable for obtaining the maximum T_c of the non-homogeneous or multi-phase material. In the industrial use zero-resistance is needed and the onset determination having high resistance shall not be used. Thus zero-point approach is appropriate for industrial use. However determination of T_c offset is very hard due to unclear zero-level. T_c is practically important in the application of superconductors. Thus standardization of determination of T_c is quite beneficial. The midpoint frequently applied for this aim in T_c determination. In this thesis, I also use midpoint approach by considering the study published for the sake of standardization (Murase et al., 2001).

In this method, first a tangential line to a part of curve in the normal state region is drawn. The value of temperature at the intersection of the transition curve and a line with 50% height of the tangential line (50% resistance) is determined as T_c . In addition two temperature values at the intersections of the transition curve and two lines with 10% and 90% heights of the tangential line are denoted by $T_{c0.1}$ and $T_{c0.9}$, respectively and the transition width, ΔT_c is defined as $T_{c0.9}$ - $Tc_{0.1}$.

Simple demonstrations of this technique are given in Fig. 4.6 for samples prepared by 400 °C and with 15% excess Mg. The resistivity curves belong to the 5 mA and 10 mA current applications, respectively. As can be viewed from these two graphs T_c can/cannot match with the 0.5 on the y-axis.

From figure 4.7 through 4.11 resistivity-temperature graphs of the samples annealed at 400 °C are given for five different currents. The resistivities in the graphs normalized to one at 50 K. T_c , T_c onset and ΔT_c values determined from each curve are listed in tables following the figures. Figure 4.9 and 4.10 illustrate impracticalness of zero point approach in T_c determination. Superconducting transition is incomplete in 100 mA measurements and T_c offset cannot be determined.

A similar analysis for 500 °C heat treated samples is demonstrated between the pages 51 and 55. To observe the effect of increasing Mg concentration on transition, 100 mA resistivity-temperature results of samples in each annealing temperature group are plotted in separate two graphs





Figure 4.6 Method of T_c , ΔT_c Determination



Figure 4.7 Resistivity-Temperature Results of Sample 400

Applied Current	T _c (K)	T _{c onset} (K)	$\Delta T_{c}(K)$	T _{c0.1} (K)	T _{c0.9} (K)
1 mA	28.1	32.42	4.75	26.26	31.01
5 mA	26.46	32.19	1.96	24.27	26.66
10 mA	27.82	33.13	5.5	25.87	30.92
50 mA	27.43	33	5.92	25	30.92
100 mA	25.97	32.42	6.7	23.54	30.24

Table 4.2 The T_c values of sample 400



Figure 4.8 Resistivity-Temperature Results of Sample 405

Applied Current	T _c (K)	T _{c onset} (K)	$\Delta T_{c}(K)$	T _{c0.1} (K)	T _{c0.9} (K)
1 mA	26.55	31.97	4.68	24.03	28.98
5 mA	25.49	34.63	5.15	23.25	28.4
10 mA	28	33.34	5.24	25.68	30.92
50 mA	26.54	33.10	6.6	23.93	30.53
100 mA	23.06	31.17	9.32	18.1	27.42

Table 4.3 The $T_{\rm c}$ values of sample 405



Figure 4.9 Resistivity-Temperature Results of Sample 410

Applied Current	T _c (K)	T _{c onset} (K)	ΔT _c (K)	T _{c0.1} (K)	T _{c0.9} (K)
1 mA	33.98	37.62	4.25	32.76	37.01
5 mA	33	38.21	5.01	30.64	35.65
10 mA	32.19	38.33	6.18	29.30	35.18
50 mA	29.93	36.89	9.11	24.6	33.71
100 mA	22.37	34.3	Not applicable	Not applicable	29.4

Table 4.4 The T_c values of sample 410



Figure 4.10 Resistivity-Temperature Results of Sample 415

Applied Current	T _c (K)	T _{c onset} (K)	$\Delta T_{c}(K)$	T _{c0.1} (K)	T _{c0.9} (K)
1 mA	29.71	36.69	6.42	26.35	32.77
5 mA	27.47	35.78	9.9	21.79	31.69
10 mA	27.19	36.4	6.43	20.76	32.75
50 mA	17.34	33	Not applicable	Not applicable	Not applicable
100 mA	Not applicable	26.22	Not applicable	Not applicable	Not applicable

Table 4.5 The $T_{\rm c}$ values of sample 415



Figure 4.11 Resistivity-Temperature Results of Sample 420

Applied Current	T _c (K)	T _{c onset} (K)	$\Delta T_{c}(K)$	T _{c0.1} (K)	T _{c0.9} (K)
1 mA	22.67	27.99	6.14	19.09	25.23
5 mA	21.79	26.55	8.24	16.46	24.7
10 mA	22.67	28.50	7.78	17.86	25.64
50 mA	21.81	29.41	10.06	15.4	26.02
100 mA	19.46	28.69	Not applicabl	Not applicable	25.1

Table 4.6 The T_c values of sample 420

In type II superconductors vortex states formation below $T_{c \text{ onset}}$ occur not only in the case of applied external magnetic field but also by the magnetic fields of electrical currents pass trough it. The magnetic field in the vortices acts on the current with a Lorentz force. The current acts in opposite direction with the same force that consecutively leads dissipative losses and voltage drop in the superconductor. The main dissipation mechanism is the scattering of the normal-phase electrons by the thermal lattice vibrations. This results with Joule losses. Another mechanism is the thermal mechanism of dissipation in which the vortex motion is accompanied by energy absorption in a region of the forward boundary of the vortex. Such a thermal gradients and heat flow cause energy dissipation (Kresin and Wolf, 1990).

As a result of these energy dissipation mechanisms increasing current in the resistivity measurement broadens the resistivity versus temperature curves and beyond some critical current zero resistance cannot be attained. This broadening is also observed in our measurement depicted through Fig. 4.7 to 4.11. The deviations from this tendency in figure 4.7 for 10 mA, in Fig. 4.8 for 1 mA and in Fig. 4.11 for 5, 10 and 50 mA are possible due to the thermal contact problems between the cold head and sample. In the figure 4.9 superconducting transition for 100 mA and in figure 4.10 that for 50 and 100 mA is incomplete.

The normalized resistivity-temperature curves given in the previous pages illustrate a general tendency of decrease in the critical current with increasing Mg concentration. High porosity of the samples prepared at 400 °C seems to prevent the passage of currents even around 50 mA and 100 mA for 10% and larger values of Mg addition. In the case of lower values of Mg concentration current can percolate through small linked cross sections. Presence of large cluster of Mg seams to be one factor reducing the net cross section to the percolation paths of supercurrents.

Other characteristic depicted by the curves is that with increasing Mg concentration, Mg dominates the resistivity behavior in the normal state and broden the resistivity curve. Latter one will be more closely examined at the last parts of the chapter.



Figure 4.12 Resistivity-Temperature Results of Sample 500

Applied Current	T _c (K)	T _{c onset} (K)	$\Delta T_{c}(K)$	T _{c0.1} (K)	T _{c0.9} (K)
1 mA	30.82	35.20	3.59	29.27	32.86
5 mA	30.63	35.23	4.56	28.59	33.15
10 mA	30.43	35.57	4.95	28.30	33.25
50 mA	28.39	34.41	6.98	25.1	32.08
100 mA	26.26	32.57	8.93	21.6	30.53

Table 4.7 The $T_{\rm c}$ values of sample 500



Figure 4.13 Resistivity-Temperature Results of Sample 505

Applied Current	T _c (K)	T _{c onset} (K)	$\Delta T_{c}(K)$	T _{c0.1} (K)	T _{c0.9} (K)
1 mA	31.89	37.13	6.17	27.9	34.07
5 mA	31.89	37.54	6.26	28.1	34.36
10 mA	31.89	37.33	6.4	27.96	34.36
50 mA	30.87	37.22	8.15	26.21	34.36
100 mA	26.80	35.70	15.72	16.89	32.60

Table 4.8 The $T_{\rm c}$ values of sample 505



Figure 4.14 Resistivity-Temperature Results of Sample 510

Applied Current	T _c (K)	T _{conset} (K)	$\Delta T_{c}(K)$	T _{c0.1} (K)	T _{c0.9} (K)
1 mA	25.65	37.13	7.77	21.40	29.17
5 mA	27.84	37.36	5.35	24.92	30.27
10 mA	28.32	37.22	5.87	25.53	31.24
50 mA	27.84	34.06	7.04	24.32	31.36
100 mA	26.50	33.21	8.62	21.65	30.27

Table 4.9 The $T_{\rm c}$ values of sample 510



Figure 4.15 Resistivity-Temperature Results of Sample 515

Applied Current	T _c (K)	T _{c onset} (K)	$\Delta T_{c}(K)$	T _{c0.1} (K)	T _{c0.9} (K)
1 mA	32.96	36.26	7.29	28	35.29
5 mA	32.90	36.28	2.97	31.47	34.44
10 mA	32.50	36.15	3.31	30.80	34.11
50 mA	31.79	36.55	3.98	29.85	33.83
100 mA	31.14	36.75	5.02	29.04	34.06

Table 4.10 The T_{c} values of sample 515 $\,$



Figure 4.16 Resistivity-Temperature Results of Samples 520

Applied Current	T _c (K)	T _{c onset} (K)	$\Delta T_{c}(K)$	T _{c0.1} (K)	T _{c0.9} (K)
1 mA	26.87	31.06	5.15	24.12	29.27
5 mA	27.62	32.77	5.92	23.83	29.75
10 mA	27.81	33.15	5.43	24.90	30.33
50 mA	25.87	32.47	7.28	22.86	30.14
100 mA	24.51	33.54	9.03	20.33	29.56

Table 4.11 The T_{c} values of sample 520 $\,$

The interruptions of superconducting transition in the resistivity-temperature measurements given in Fig. 4.9 and 4.10 for 50 and 100 mA were not observed in the samples prepared by a 500 °C heat treatment. These two figures indicate that a 100 °C increase in heat treatment leads to an improvement in critical current of the samples. That increase may be caused by an increase in the MgO concentration that acts as pinning center, grain refinement and better grain linkages.

The presence of MgO with small grain sizes has been suggested as a possible pinning center (Zhao et al., 2002) Pinning centers prevent the motion of vortex states and so the energy dissipation to some extent.

Table 3.1 and the SEM images indicate a consolidation and better grain linkage with increasing heat treatment. Such an increase in the grain linkage has been reported in many studies as previously mentioned in this text. It decreases weak link problems.

Although usually grain refinements in MgB_2 occur by drawing and rolling processes, the results obtained from examination of SEM image suggest presence of such a refinement in the 500 °C. Grain refinement increases grain boundary pinning which in turn increases pinning enhancement (Zhoa et al, 2002).

The resistivity-temperature results given through Fig. 4.12 to 4.16 illustrate the effect of increasing Mg concentration on transition. The increases in the slope of the curves in normal state arise from relatively lower resistance of Mg with respect to MgB₂. In addition Table 4.7, 4.8 and 4.10 point out a tendency of improvement in critical temperature. While aberration from this tendency in the resistivity-temperature results of the sample including 10 wt% excess Mg probably a result of thermal contact problem in the measurements, that for the sample with 20 wt% excess Mg most likely due to the weak link problems aroused by large clusters of Mg. The latter case will further examined after Fig. 4.17 and 4.18 that illustrates the effect of Mg concentration on resistive transition behavior.



Figure 4.17 10 mA Resistivity-Temperature results of 400 °C heat-treated pellets.

Applied Current	T _c (K)	T _{c onset} (K)	$\Delta T_{c}(K)$	T _{c0.1} (K)	T _{c0.9} (K)
Pure	27.82	33.13	5.5	25.87	30.92
+5% Mg	28	33.34	5.24	25.68-	30.92
+10% Mg	32.19	38.33	6.18	29.30	35.18
+15% Mg	27.19	36.4	6.43	20.76	32.75
+20% Mg	22.67	28.50	7.78	17.86	25.64

Table 4.12 The T_{c} values of the samples



Figure 4.18 10 mA resistivity-temperature results of 500 °C heat-treated pellets.

Applied Current	T _c (K)	T _{c onset} (K)	$\Delta T_{c}(K)$	T _{c0.1} (K)	T _{c0.9} (K)
Pure	30.43	35.57	4.95	28.30 K	33.25 K
+5% Mg	31.89	37.33	6.4	27.96 K	34.36 K
+10% Mg	28.32	37.22	5.87	25.53 K	31.24 K
+15% Mg	32.50	36.15	3.31	30.80 K	34.11 K
+20% Mg	27.81	33.15	5.43	24.90 K	30.33 K

Table 4.13 The T_{c} values of the samples

Most evident effect of increasing Mg constituents in the Fig. 4.17 and 4.18 is an increase in slope of the resistivity curve above the transition temperature. In normal state the resistivity-temperatures graphs of samples including excess Mg has a slope strongly depends on the Mg concentration and when the superconducting transition begin this slope suddenly increases. The change in the slope above the $T_{c \text{ onset}}$ results from temperature dependence of Mg resistance. Mg has relatively lower resistance compared to MgB₂ and with increasing concentration of Mg the resistivity of the curve above $T_{c \text{ onset}}$ suppressed. Under the $T_{c \text{ onset}}$ current percolate through superconducting MgB₂ phases and slope in this part mainly determined by superconducting MgB₂ phases and consequently by their grain connectivity, grain size, porosity and purity. The broadening is an undesired effect especially when the T_c zero decreases considerably.

As revealed from graphics a 100 °C increase in heat treatment in this temperature range leads an improvement in T_c and T_c onset values and a 0.55 K decreases ΔT_c for pure samples. This is probably a result of increases in grain connectivity and better fuse of Mg in empty spaces by decreasing porosity of the sample. For 400 °C heat-treated samples this increase in T_c continues up to 10% Mg addition. The value of the improvement is around 4.37 K. On the other hand T_{c onset} gets higher values up to 15% Mg addition and maximum value is reached for the sample with 10% excess Mg. The amount of increase in T_{c onset} for sample 410 relative to that of pure sample is 5.2K. Similar case is also valid for samples prepared by 500 °C heat-treatment with some exceptions. For these samples T_c continue to increase up to 15% Mg addition. The maximum magnitude of the increase in the T_c is obtained for sample 515 and that in the T_{c onset} is reached for sample 505. The magnitudes of increases are about 2.07 K and 1.76 K, respectively. Although T_{c onset} value is better for 500 °C heat-treated one among the pure samples, in the case of Mg substitution a best value is obtained for the sample 410. While ΔT_c increases with increasing concentration of Mg for the 400 °C heattreated sample, fluctuate with increasing Mg concentration for the 500 °C heat-treated samples. The reason of these fluctuations is probably a thermal contact problem with the sample and cold heat.

In spite of the slight increase of T_c in sample 410 relative to sample 400, vice versa is valid for $T_{c zero}$ for these samples. The reason of this relative reduction in $T_{c zero}$ might be inhomogeneous grain distribution with different T_c values. Different grains can have different T_c values due to the dimensions of MgB₂ and the thickness of Mg layers around them. In the case of direct junction between a superconductor and a normal

metal, the overlap of the wave functions causes the density n_s of electron pairs to differ in the neighborhood of the surface from its value in the bulk. The presence of such an interface causes leakage of some quasi particles into superconductor and leakage of some cooper pairs to the normal metal. This effect is called as proximity effect. The proximity effect generally results with the suppression of the superconducting properties like T_c.(in some rare cases enhancement is possible and these are called as inverse proximity effect) After some characteristic thickness of normal layer no further reduction in T_c of superconductor is occur and if the thickness of the superconductor larger than the coherence length, irrespective of the normal layer thickness T_c does not show considerable change. In our samples Mg is not distributed homogenously in the sample, as a result of this we have many parts in the sample with a variety of T_c values. Hence all of these grains become superconductor at different temperature and a broadening result. According to this the broadening observed in transition of our samples can be caused by proximity effect. Even with resistivity measurements it is not possible to examine the transition behavior of the whole substance, still the broadening can attributed to the proximity effect and disorder. The hypothesis seems to be supported by the explanation of relative superconducting transition broadening in magnetization measurements of the MgB₂/Al and MgB₂/Mg composite pellets with the proximity effect and disorder (Sharoni et al., 2001, Dunand, 2001). Compared to composite forms all the part of the pure substance past to superconducting state almost at the same temperature. This is the reason of the sharp transition and higher T_{c onset} in the sample 400. The higher value of T_c and T_{c onset} in the samples containing excess Mg might be due to the formation of percolation paths by presence of thin layer of Mg between superconducting MgB₂ grains. This layer can show superconducting properties as a result of proximity effect. Existence of such paths can increase T_c and T_{c onset}, which is lower in pure sample 400 because of large distances between grains and the interruption of supercurrent through such a kind of large distances.

20% Mg addition suppresses both the T_c and T_c _{onset} values of samples for both 400 °C and 500 °C heat treatment with respect to pure samples subjected to similar heat treatments. In addition a broadening in ΔT_c is observed for these samples. While the magnitude of this broadening is 2.28 K for 400 °C, that for 500 °C is 0.48 K.

CHAPTER 5

CONCLUSIONS

It is difficult to use MgB_2 in bulk applications due to its brittleness. Fortunately, it is possible to improve the mechanical properties either by cladding of MgB_2 cores with a ductile metallic sheaths or by the fabrication of a metal matrix composites. In this study, we have used the latter approach. By doing so, we hope the benefit from the heat and electrical conductivity of the metal in the case of localized break down in the superconductivity of the MgB_2 phase and improve the crack arrest and toughness of the bulk material.

The XRD and SEM studies indicate the possible presence of small quantities of second phases like MgO, MgB₄, MgB₆. While presence of MgB₄ and MgB₆ may cause weak link problems, the data point to the source of these phases as commercial powders and so they are not main source of the broadening in the superconducting transition of our samples. Existing MgO can act as a pinning center and concurrently can enhance the superconducting critical current. Increasing concentration of MgO with increasing Mg concentration and heat might be one of the factors enhancing the supercurrent in the 500 °C heat-treated samples relative to that of 400 °C. The resistivity curves for various currents imply a general tendency of decrease in the critical current with increasing Mg concentration. High porosity of the samples prepared at 400 °C seem to prevent the passage of currents even around 50 mA and 100 mA for 10% and larger values of Mg addition. On the other hand lower currents can be superconducted through small linked cross sections. Presence of large cluster of Mg seams to be one factor interrupting the net cross section of the percolation paths of supercurrents.

Although the Mg did not diffuse deep in to whole the grain boundaries homogenously, the presence of it up to some extent increases the T_c of the samples due to the formation of percolation paths as a result of proximity effect.

A 100 °C increases in heat treatment in the temperature range leads an improvement in T_c and $T_{c \text{ onset}}$ values and a decrease in ΔT_c for pure samples for 10 mA resistivity measurements. This is probably a result of increases in grain connectivity and better fuse of Mg in empty spaces by decreasing the porosity of the samples. In our temperature range increasing heat treatment enhanced the grain linkage and concomitantly decreases the weak link problems resulting from poor grain connectivity and highly porous structure of the pellets. Furthermore the SEM images and the ratio of empirical density to theoretical density denote a decrease in porosity with increasing Mg concentration and temperature. While an increase in T_c continues up to 10% Mg addition for the lower heat treatment, it continues up to 15% Mg addition for the higher heat treatment and the best value is attained by 500 °C heat treated one. In addition while ΔT_c increases with increasing concentration of Mg for the 400 °C heat-treated sample, fluctuate with increasing Mg concentration for the 500 °C heat treated samples. The reason of these fluctuations is probably a thermal contact problem with the sample and cold heat. One of the feasible sources for the broadening of superconducting transition in the resistivity-temperature measurements is the proximity effect. MgB₂ grains in contact with the Mg have different T_c according to their relative thickness to each other, coherence length and characteristic thickness of normal state. The presence of the grain with different T_c on the percolation paths results in a broadening of superconducting transition in the resistivity curves. The presence of large areas of Mg and disorder is the supporting factor in the broadening.

Compared to composite forms, all the part of the entire pure substance past to superconducting state almost at the same temperature. This is the reason of the sharp transition and higher $T_{c \text{ onset}}$ in the pure samples. The higher value of T_c and $T_{c \text{ onset}}$ in case of presence of extra Mg might be due to the formation of percolation paths by presence of thin layer of Mg between superconducting MgB₂ grains. This layer can show superconducting properties as a result of proximity effect and results in the formation of these paths.

Most evident effect of increasing Mg constituents in the samples is increasing slope of the resistivity curve at temperatures above the $T_{c \text{ onset}}$. This slope is directly correlated with the Mg concentration and temperature dependence of Mg resistance. Without Mg substitution resistivity curve follow a path with a zero slope and a very sharp superconducting transition occur. Under the $T_{c \text{ onset}}$ current penetrate through superconducting MgB₂ phases and slope in this part mainly determined by superconducting MgB₂ phases and in turn with proximity effect, their grain connectivity, grain size, porosity, and distribution of impurities.

All the results indicates that beyond some Mg concentration further Mg addition suppresses both the T_c and $T_{c \text{ onset}}$ values of samples for the both temperature like in the case of 20% Mg addition. In addition an extra broadening is observed for these samples. The broadening is an undesired effect especially when the T_c offset decreases considerably.

Although the present data indicates an improvement in superconducting properties of the samples with increasing temperature in our range and Mg concentration to some extend, all these interpretations made by considering the existing resistivity curves do not lead a certain understanding of the superconducting transition mechanism and properties of the Mg/MgB₂ composite fabricated during this study. As pointed out before, resistivity curves may demonstrate the superconducting transition of only a small part of the whole sample. To obtain data corresponding to the superconducting transition of entire bulk, magnetization measurement should be carried out. The existing data only suggest a possible increase in T_c of sample annealed at a temperature around 500 °C with increasing Mg concentration up to some value between 15% and 20%, and an increase in critical current relative to samples annealed at 400 °C.

APPENDIX

Table A-1 Characteristics of Mg

Theoretical Density	1.738 gr/cm^3		
Atomic Weight	24.3050		
Atomic Number	12		
Molar Volume	14 cm^3		
Melting Point	650 °C		
Boiling Point	1090 °C		
Crystal Structure	Hexagonal Close-Packed		
	a=320.94		
Hexogonal Lattice Parameters	c=521.08		
Superconduction Temperature	No data		
Electrical Resistivity	440 μΩcm		
Atomio Dadius	Empirical radius 150 pm		
Atomic Radius	Calculated radius 145 pm		
Young Modulus	45 GPa		
Bulk Modulus	45 Gpa		
Rigidity Modulus	17 GPa		
Hardness	2.5		

Data in the table obtained from web page

http://www.webelements.com/webelements/elements/text/Mg

|--|

Parameter	Values		
Formula Weight	45.93		
Theoritical Density	ρ = 2.625 g cm ⁻³		
Melting Point	800 ⁰ C		
Hevogonal Lattice Parameters	a=3.0855±0.0006 A°		
Trexogonal Lattice I arameters	c=3.522±0.002 A°		
Critical Temprature	$T_c = 39-40 \text{ K}$		
Carrier Density	$n_s = 1.7 - 2.8 \times 10^{23} \text{ holes/cm}^3$		
Penetration Depth	$\lambda(0) = 85 - 180 \text{ nm}$		
Calamara I anotha	$\xi_{ab=}$ 3.7–12 nm		
Concrence Lengths	$\xi_{c=} 1.6 - 3.6 \text{ nm}$		
Pressure coefficient	$dT_c/dP = -11 - 2 \text{ K/GPa}$		
Energy Gap	$\Delta(0) = 1.8 - 7.5 \text{ meV}$		
	$J_c(4.2 \text{ K}, 0\text{T}) > 10^7 \text{ A/cm}^2$		
	$J_c(4.2 \text{ K}, 4\text{T}) \sim 10^6 \text{ A/cm}^2$		
Critical Current Densities	$J_c(4.2 \text{ K}, 10\text{T}) > 10^5 \text{ A/cm}^2$		
	$J_c(25 \text{ K}, 0\text{T}) > 5 \times 10^6 \text{ A/cm}^2$		
	$J_c(25 \text{ K}, 0\text{T}) > 10^5 \text{ A/cm}^2$		
Resistivity Near T _c	$\rho(40 \text{ K}) = 0.4 - 16 \mu \Omega \text{cm}$		
Resistivity Ratio	RR= $\rho(40 \text{ K})/\rho(300 \text{ K})=0.5-27$		
Upper critical fields	$H_{c2}^{ab}(0) = 14 - 39 \text{ T}$		
	$H_{c2}^{c}(0)=2-24 \text{ T}$		
Lower Critical Field	$H_{c1}(0)=27-48 \text{ mT}$		

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